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FGH50T65SQD 650 V, 50 A Field Stop Trench IGBT

Features

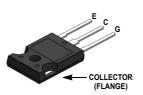
- Maximum Junction Temperature : T_J =175°C
- · Positive Temperaure Co-efficient for Easy Parallel Operating
- · High Current Capability
- Low Saturation Voltage: V_{CE(sat)} =1.6 V(Typ.) @ I_C = 50 A
- 100% of the Parts Tested for I_{LM}(1)
- · High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- · RoHS Compliant

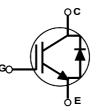
General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 4th generation IGBTs offer the optimum performance for solar inverter, UPS, welder, telecom, ESS and PFC applications where low conduction and switching losses are essential.

Applications

· Solar Inverter, UPS, Welder, Telecom, ESS, PFC





Absolute Maximum Ratings

Symbol	Description		FGH50T65SQD_F155	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		± 20	V
	Transient Gate to Emitter Voltage		± 30	V
I _C	Collector Current	@ T _C = 25°C	100	А
ιC.	Collector Current	@ T _C = 100 ^o C	50	А
I _{LM (1)}	Pulsed Collector Current	@ T _C = 25°C	200	А
I _{CM (2)}	Pulsed Collector Current		200	А
I _F	Diode Forward Current	@ T _C = 25°C	50	А
	Diode Forward Current	@ T _C = 100 ^o C	30	А
I _{FM}	Pulsed Diode Maximum Forward Curr	200	А	
P _D	Maximum Power Dissipation	@ T _C = 25°C	268	W
. D	Maximum Power Dissipation	@ T _C = 100 ^o C	134	W
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes: 1. V_{CC} = 400 V, V_{GE} = 15 V, I_{C} = 200 A, R_{G} = 3 $\Omega,$ Inductive Load

2. Repetitive rating: Pulse width limited by max. junction temperature

April 2016

Symbo	ol 🛛	P	arameter	r FGH		50T6	5SQD_F155		Unit	
R _{0JC} (IGBT)	Therm	al Resistance, Jur	nction to Case	se, Max.		0.56			°C/W	
R _{0JC} (Diode) Therm	Thermal Resistance, Junction to Ca		e, Max.		1.25			°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to An			ient, Max.			40		°C/W	
Package	e Markir	ng and Orde	ering Inf	ormation						
Part N		Top Mark	Package		dReel	Size	Tape Widtl	n Qty p	er Tube	
FGH50T65	SQD_F155	FGH50T65SQD	TO-247 G0	3 Tube	-		-		30	
Electric	al Chara	acteristics o	of the IG	BT $T_{C} = 25^{\circ}C$ unless other	wise noted					
Symbol		Parameter		Test Conditio	ns	Mi	n. Typ.	Max.	Unit	
Off Charac	teristics									
BV _{CES}	Collector to	Emitter Breakdow	vn Voltage	/ _{GE} = 0V, I _C = 1 mA		65	0 -	-	V	
ABV Tomporature Coefficient of Breakdown		reakdown	$I_{\rm C}$ = 1 mA, Reference to 25°C		-	0.6	-	V/ºC		
I _{CES}	Collector Cut-Off Current		Ň	V _{CE} = V _{CES} , V _{GE} = 0 V		-	-	250	μA	
I _{GES}	G-E Leakage Current		١	V_{GE} = V_{GES} , V_{CE} = 0 V		-	-	±400	nA	
On Charac	teristics									
V _{GE(th)}		G-E Threshold Voltage		I _C = 50 mA, V _{CE} = V _{GE}		2.0	6 4.5	6.4	V	
			I _C = 50 A, V _{GE} = 15 V, T		_C = 25°C	-	1.6	2.1	V	
V _{CE(sat)}	Collector to	Emitter Saturatio	n Voltage	_C = 50 A, V _{GE} = 15 V, T _C	_c = 175°C	-	1.92	-	V	
Dynamic C	haracteristi	cs								
C _{ies}	Input Capa	citance				-	3275	-	pF	
C _{oes}	Output Cap	Output Capacitance Reverse Transfer Capacitance		V _{CE} = 30 V _, V _{GE} = 0 V, f = 1MHz		-	84	-	pF	
C _{res}	Reverse Tr					-	12	-	pF	
Switching	Characteris	tics								
t _{d(on)}	Turn-On De	elay Time				-	22	-	ns	
t _r	Rise Time	ïme				-	8.7	-	ns	
t _{d(off)}	Turn-Off De	elay Time	١	/ _{CC} = 400 V, I _C = 12.5 A	λ,	-	105	-	ns	
t _f	Fall Time			R_G = 4.7 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25 ^o C		-	2.5	-	ns	
E _{on}	Turn-On Sv	witching Loss	1			-	180	-	uJ	
E _{off}	Turn-Off Sv	witching Loss				-	45	-	uJ	
E _{ts}	Total Switc	hing Loss				-	225	-	uJ	
t _{d(on)}	Turn-On De	elay Time				-	19	-	ns	
t _r	Rise Time					-	13	-	ns	
t _{d(off)}	Turn-Off De	Turn-Off Delay Time Fall Time		/ _{CC} = 400 V, I _C = 25 A,		-	93	-	ns	
t _f	Fall Time			R _G = 4.7 Ω, V _{GE} = 15 V,		-	6.4	-	ns	
E _{on}	Turn-On Sv	witching Loss		Inductive Load, T _C = 25 ^o	Ċ	-	410	-	uJ	
E _{off}	Turn-Off Sv	witching Loss				-	88	-	uJ	
E _{ts}	Total Switc	hing Loss				-	498	-	uJ	

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
t _{d(on)}	Turn-On Delay Time		-	20	-	ns
t _r	Rise Time		-	9.8	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 12.5 A,	-	116	-	ns
t _f	Fall Time	$R_{G} = 4.7 \Omega$, $V_{GE} = 15 V$,	-	3.5	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T _C = 175 ^o C	-	402	-	uJ
E _{off}	Turn-Off Switching Loss		-	110	-	uJ
E _{ts}	Total Switching Loss		-	512	-	uJ
t _{d(on)}	Turn-On Delay Time		-	18	-	ns
t _r	Rise Time	V _{CC} = 400 V, I _C = 25 A, R _G = 4.7 Ω, V _{GE} = 15 V,	-	15	-	ns
t _{d(off)}	Turn-Off Delay Time		-	102	-	ns
t _f	Fall Time		-	8	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T _C = 175 ^o C	-	641	-	uJ
E _{off}	Turn-Off Switching Loss		-	203	-	uJ
E _{ts}	Total Switching Loss		-	844	-	uJ
Qg	Total Gate Charge		-	99	-	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 50 A, V _{GE} = 15 V	-	17	-	nC
Q _{gc}	Gate to Collector Charge		-	23	-	nC

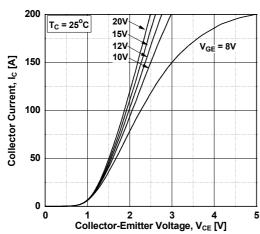
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Electrical Characteristics of the Diode T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V _{FM}	Diode Forward Voltage	I _F = 30 A	T _C = 25 ^o C	-	2.2	2.6	V
		1 _F 0077	T _C = 175 ^o C	-	1.9	-	•
E _{rec}	Reverse Recovery Energy		T _C = 175 ^o C	-	40	-	uJ
t _{rr}	Diode Reverse Recovery Time	I _F =30 A, dI _F /dt = 200 A/μs	T _C = 25°C	-	31	-	ns
11			T _C = 175°C	-	207	-	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	-	48	-	nC
~11			T _C = 175 ^o C	-	820	-	

Typical Performance Characteristics







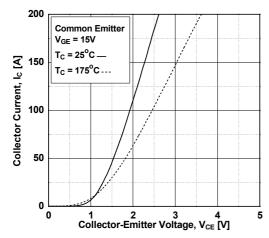


Figure 5. Saturation Voltage vs. V_{GE}

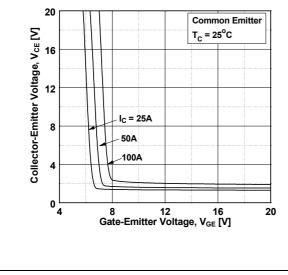
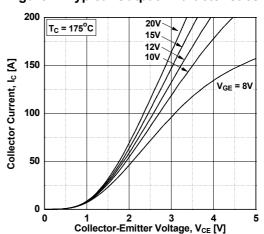


Figure 2. Typical Output Characteristics





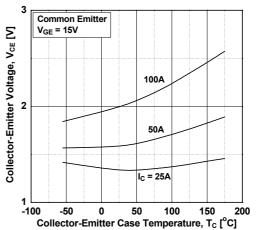
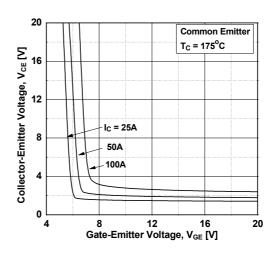
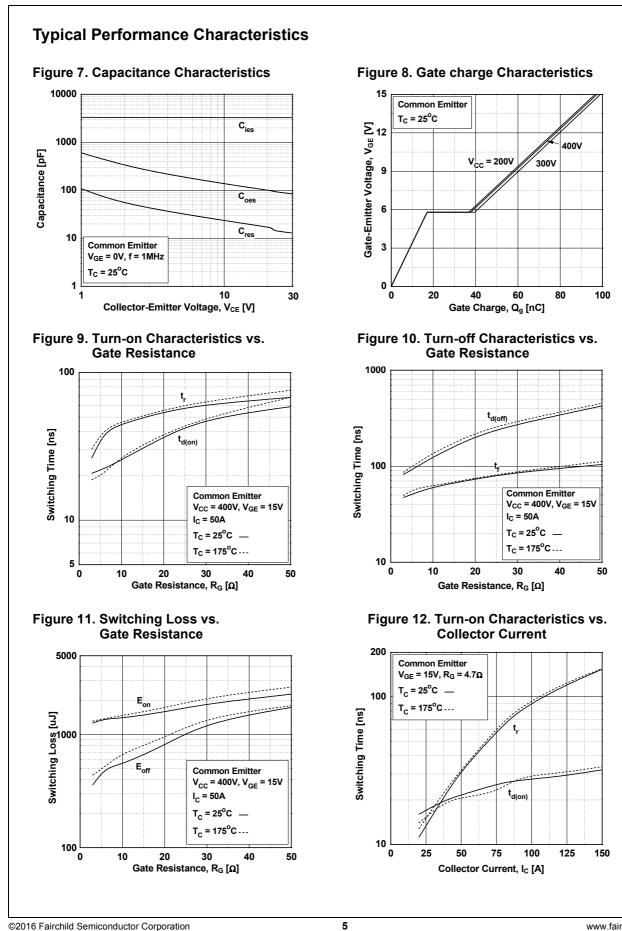


Figure 6. Saturation Voltage vs. V_{GE}

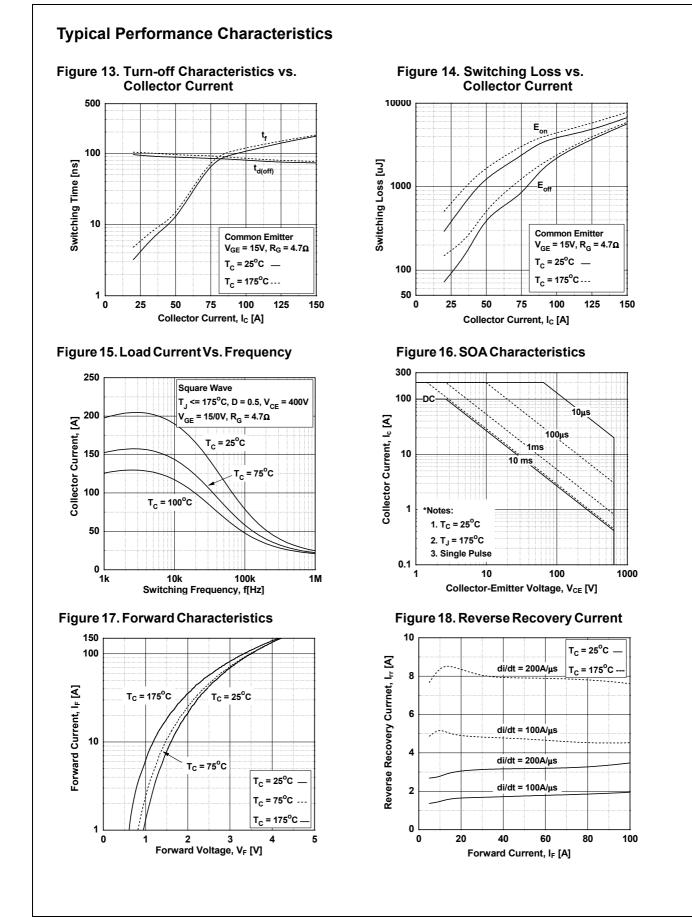


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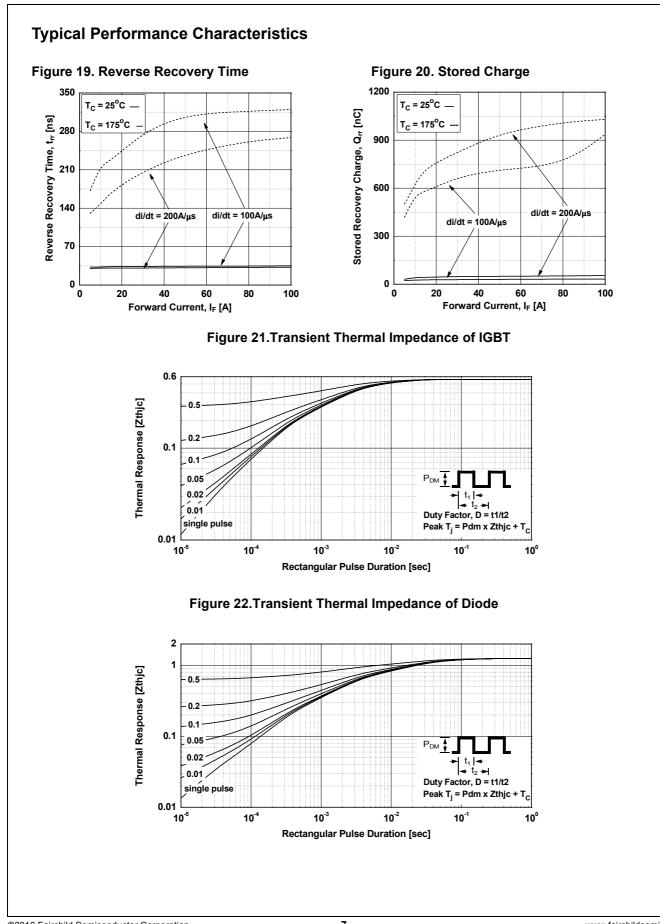


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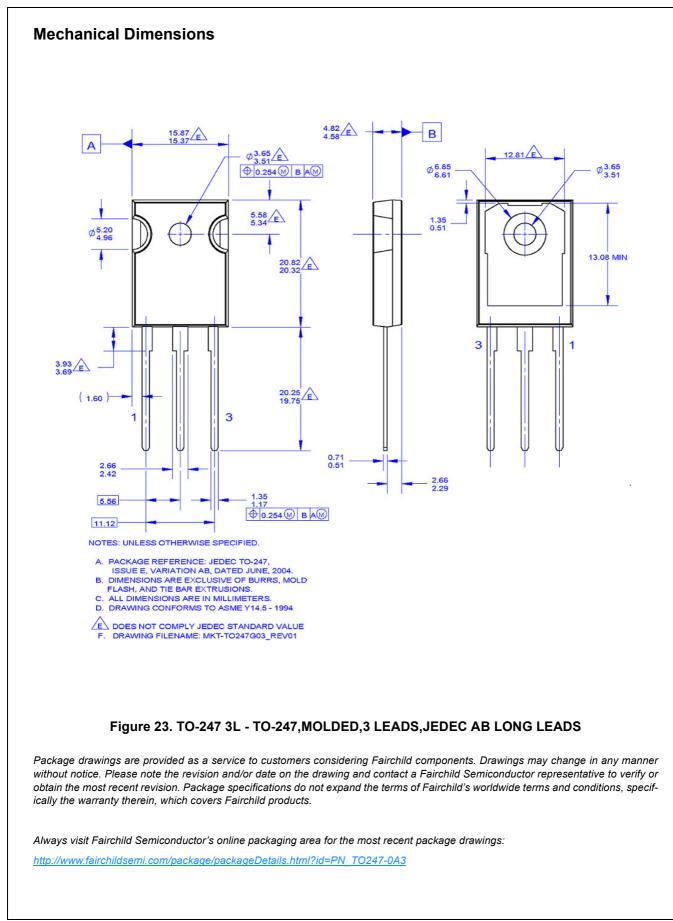
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